

2SK1529

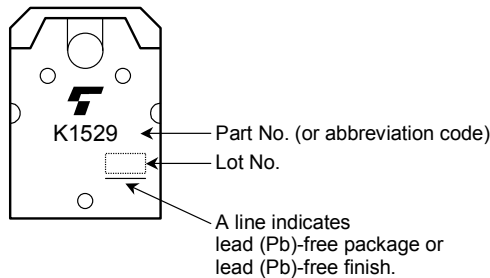
High-Power Amplifier Application

- High breakdown voltage : $V_{DSS} = 180V$
- High forward transfer admittance : $|Y_{fs}| = 4.0 S$ (typ.)
- Complementary to 2SJ200

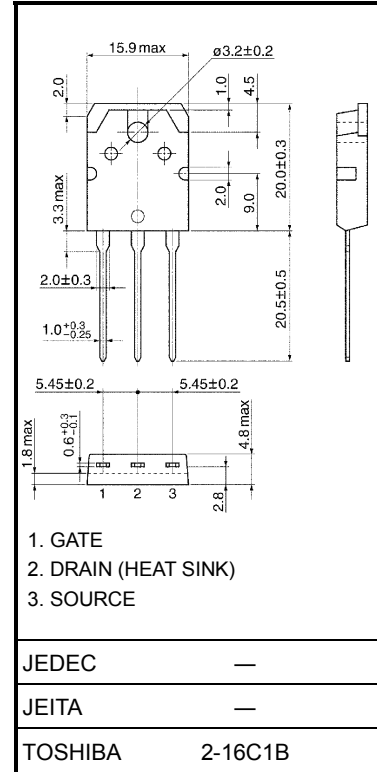
Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	180	V
Gate-source voltage	V_{GSS}	±20	V
Drain current (Note 1)	I_D	10	A
Drain power dissipation (Tc = 25°C)	P_D	120	W
Channel temperature	T_C	150	°C
Storage temperature range	T_{stg}	-55~150	°C

Marking



Unit: mm



Weight: 4.6 g (typ.)

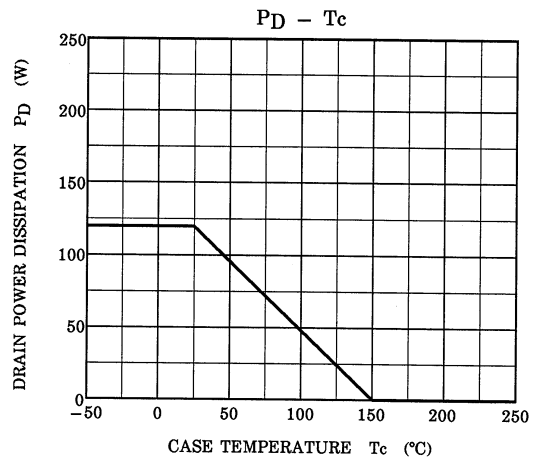
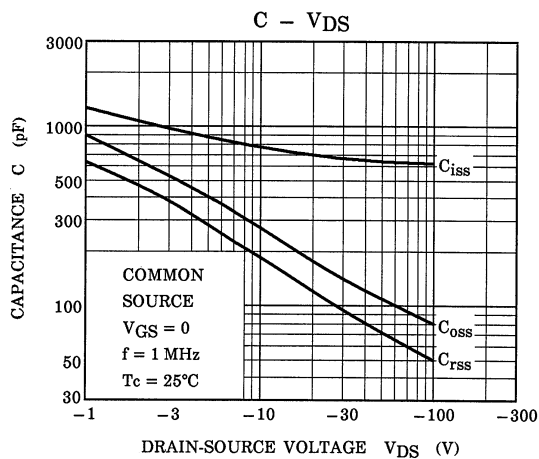
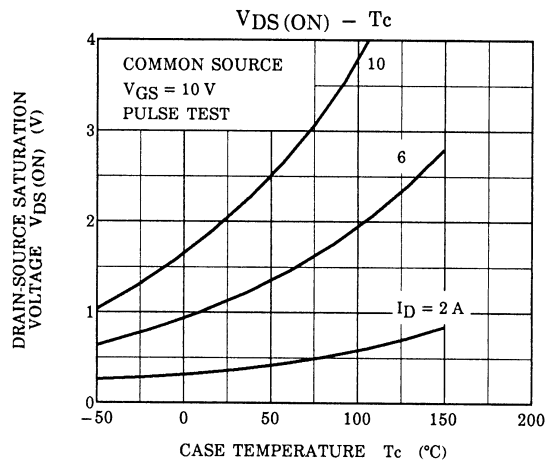
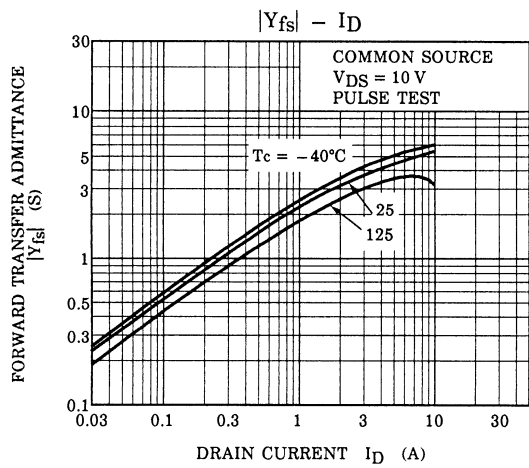
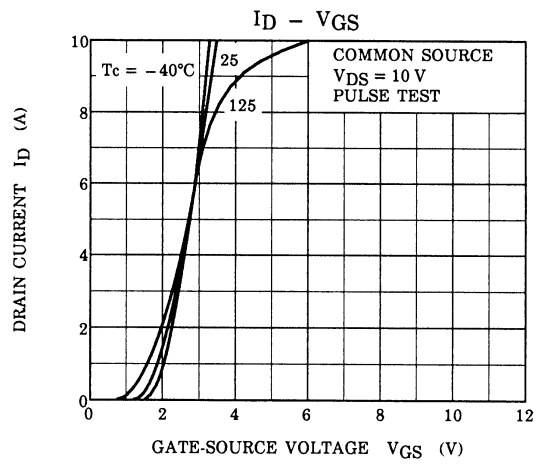
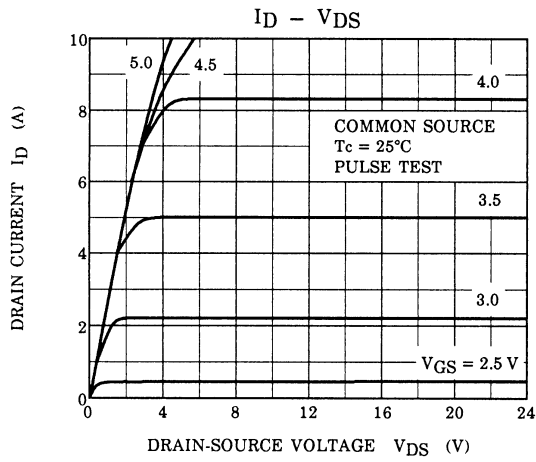
Electrical Characteristics (Ta = 25°C)

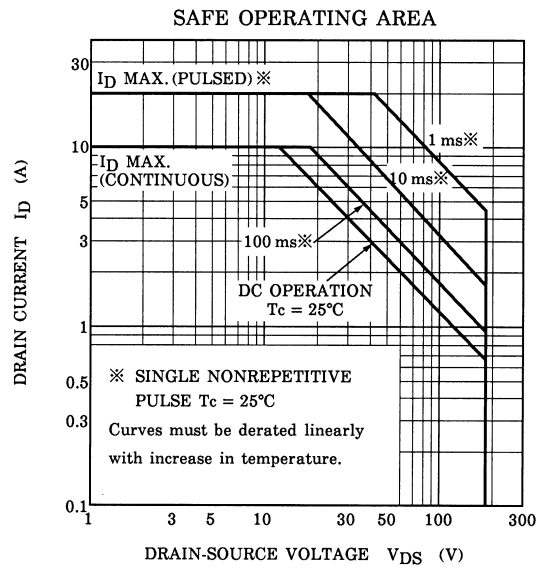
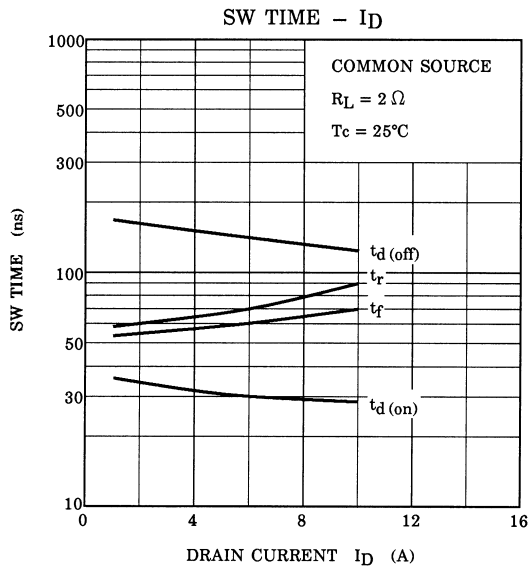
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain cut-off current	I_{DSS}	$V_{DS} = 180 V, V_{GS} = 0$	—	—	1.0	mA
Gate leakage current	I_{GSS}	$V_{DS} = 0, V_{GS} = \pm 20 V$	—	—	±0.5	µA
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10 mA, V_{GS} = 0$	180	—	—	V
Drain-source saturation voltage	$V_{DS(ON)}$	$I_D = 6 A, V_{GS} = 10 V$	—	2.5	5.0	V
Gate-source cut-off voltage (Note 2)	$V_{GS(OFF)}$	$V_{DS} = 10 V, I_D = 0.1 A$	0.8	—	2.8	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10 V, I_D = 3 A$	—	4.0	—	S
Input capacitance	C_{iss}	$V_{DS} = 30 V, V_{GS} = 0, f = 1 MHz$	—	700	—	pF
Output capacitance	C_{oss}	$V_{DS} = 30 V, V_{GS} = 0, f = 1 MHz$	—	150	—	
Reverse transfer capacitance	C_{rss}	$V_{DD} = 30 V, V_{GS} = 0, f = 1 MHz$	—	90	—	

Note 1: Ensure that the channel temperature does not exceed 150°C.

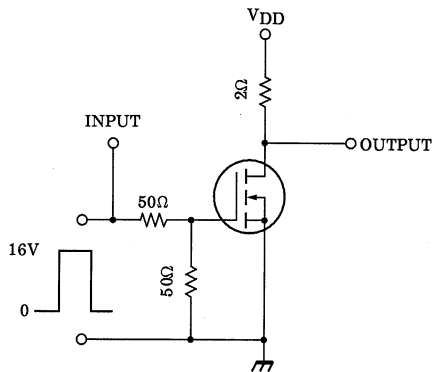
Note 2: $V_{GS(OFF)}$ Classification 0: 0.8~1.6 Y: 1.4~2.8

This transistor is an electrostatic-sensitive device.
 Please handle with caution.

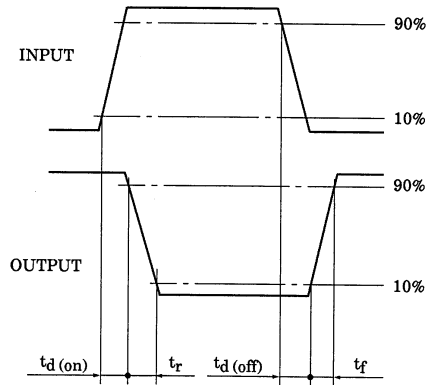




Switching Time Test Circuit



Waveforms



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